NSN 5961-01-024-5793

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-024-5793 **Inclosure Material:** Glass and metal **Overall Length:** 1.550 inches **Overall Diameter:** 1.063 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-8 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.240 inches and 1.250 inches **Thread Size:** 0.375 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.60 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Item must comply with rqmt of desc production standard no. L02139 for navy nuclear propulsion plant products only **Thread Series Designator: Terminal Type And Quantity:** 1 insulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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